Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material: Metal **Overall Length:** Between 0.160 inches and 0.180 inches **Terminal Length:** 1.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Component Name And Quantity:** 2 transistor **Mounting Method:** Terminal **Terminal Circle Diameter:** 0.200 inches **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 40.0 collector to base voltage, dc all transistor and 15.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector absolute all transistor Maximum Operating Tempurature Per Measurement Point: 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a Unit Of Measure: --**Demilitarization:** No Fiig: A110a0